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ADD-A-PAK Generation VII Power Modules Standard Diodes, 60 A



PRODUCT SUMMARY					
I _{F(AV)}	60 A				
Туре	Modules - Diode, High Voltage				
Package	ADD-A-PAK				
Circuit	Two diodes doubler circuit, Two diodes common cathode, Two diodes common anode, Single diode				

MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- High voltage
- Industrial standard package
- · Low thermal resistance
- UL approved file E78996
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- Up to 1600 V
- High surge capability
- Easy mounting on heatsink

ELECTRICAL DESCRIPTION

These modules are intended for general purpose high voltage applications such as high voltage regulated power supplies, lighting circuits, temperature and motor speed control circuits, UPS and battery charger.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES				
I _{F(AV)}	114 °C	60				
I _{F(RMS)}	94		А			
I	50 Hz	1300	A			
I _{FSM}	60 Hz	1360				
l ² t	50 Hz	8.44	kA ² s			
141	60 Hz	7.68	KA-S			
l²√t		84.5	kA²√s			
V _{RRM}	Range	400 to 1600	V			
TJ		-40 to 150	°C			
T _{Stg}		-40 10 150	U			

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = 150 °C mA			
	04	400	500				
	06	600	700				
	08	800	900				
VS-VSK.56	10	1000	1100	10			
	12	1200	1300				
	14	1400	1500				
	16	1600	1700				

FORWARD CONDUCTION						
PARAMETER	SYMBOL	TEST CONDITIONS			VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° condu	iction, half sine	wave	60 114	A °C
Maximum RMS forward current	I _{F(RMS)}	DC at 90 °C	case temperat	ure	94	0
	(-)	t = 10 ms	No voltage		1300	
Maximum peak, one-cycle forward,		t = 8.3 ms	reapplied	-	1360	A
non-repetitive surge current	IFSM	t = 10 ms	100 % V _{RRM}		1090	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1140	
	Maximum I ² t for fusing $I^{2}t$ $I^{$	intitial $T_J = T_J$ maximum	8.44			
N		t = 8.3 ms	reapplied	-	7.68	kA ² s
Maximum -t for fushing		t = 10 ms	100 % V _{RRM}		5.97	
		t = 8.3 ms	reapplied		5.43	
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms t	o 10 ms, no vol	tage reapplied	84.5	kA²√s
Low level value of threshold voltage	V _{F(TO)1}	(16.7 % x π	$x I_{F(AV)} < I < \pi x$	(I _{F(AV)}), T _J = T _J maximum	0.74	V
High level value of threshold voltage	V _{F(TO)2}	$(I > \pi \times I_{F(AV)})$	$(I > \pi x I_{F(AV)}), T_J = T_J maximum$			v
Low level value of forward slope resistance	r _{f1}	(16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum		(I _{F(AV)}), T _J = T _J maximum	3.94	mΩ
High level value of forward slope resistance	r _{f2}	$(I > \pi \times I_{F(AV)}), T_J = T_J maximum$		3.43	11122	
Maximum forward voltage drop	V _{FM}	$I_{FM} = \pi \times I_{F(x)}$	_{AV)} , T _J = 25 °C,	t _p = 400 μs square wave	1.6	V

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum peak reverse leakage current	I _{RRM}	T _J = 150 °C	10	mA		
Maximum RMS insulation voltage	V _{INS}	50 Hz	3000 (1 min) 3600 (1 s)	V		

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THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Junction and storage temperature ra	ange T _J , T _{Stg}		-40 to 150	°C	
Maximum internal thermal resistance junction to case per leg	e, R _{thJC}	DC operation	0.33	°C/W	
Typical thermal resistance, case to heatsink per module	R _{thCS}	R _{thCS} Mounting surface flat, smooth and greased		0/10	
to heat	tsink	A mounting compound is recommended and the	4	Nirro	
Mounting torque ± 10 % — bu	sbar	torque should be rechecked after a period of 3 hours to allow for the spread of the compound.	3	Nm	
Approximate weight			75	g	
			2.7	oz.	
Case style		JEDEC [®]	ADD-A-PAK Ger	n. VII (TO-240AA)	

DEVICES	SINE HALF WAVE CONDUCTION					RE	CTANGUL	AR WAVE C	CONDUCTIO	Л	
DEVICES	180°	120°	90°	60°	30°	180°	120°	90°	60°	30 °	
VSK.56	0.115	0.136	0.173	0.236	0.346	0.09	0.145	0.185	0.243	0.349	°C/W

Note

• Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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DC

Period

100

100

Conduction

60

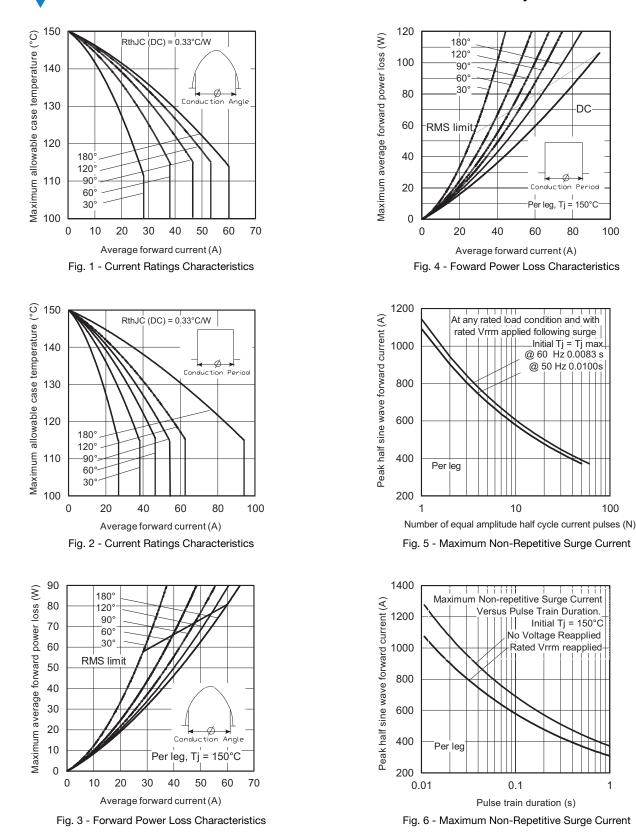
Per leg, Tj = 150°C

80

Initial Tj = Tj max

@ 60 Hz 0.0083 s @ 50 Hz 0.0100s

Initial Tj = 150°C



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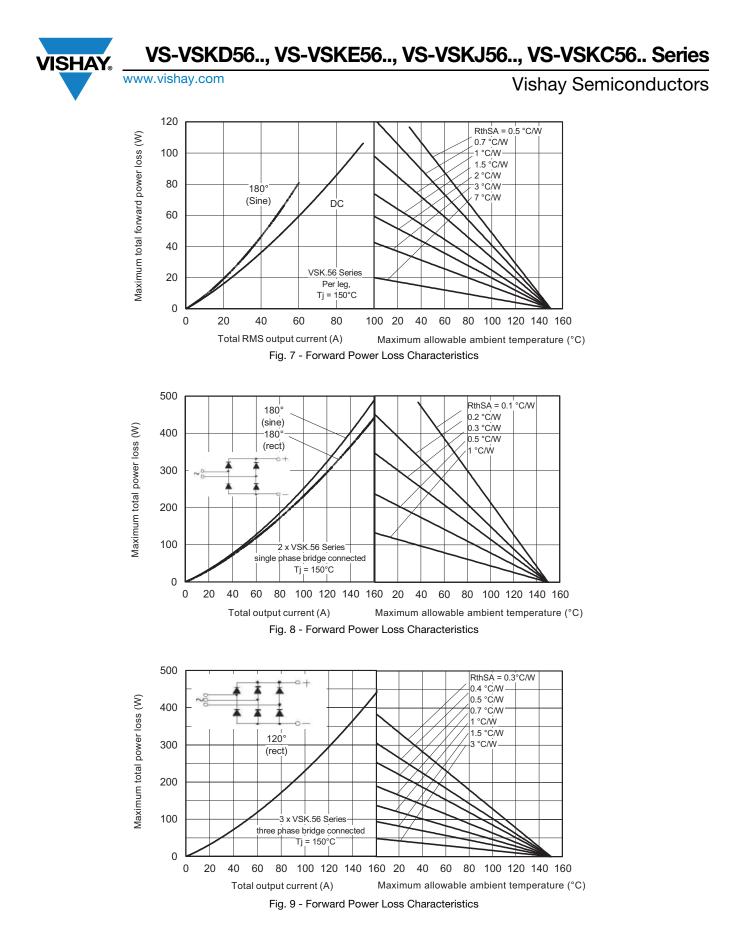
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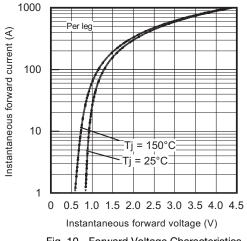


Fig. 10 - Forward Voltage Characteristics

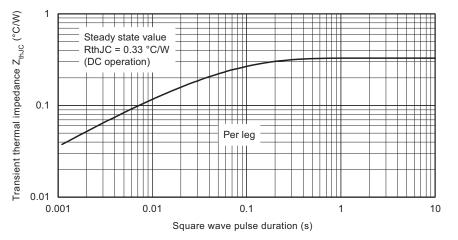
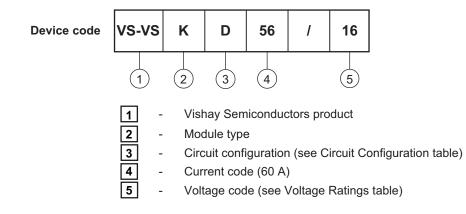


Fig. 11 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE



Note

To order the optional hardware go to <u>www.vishay.com/doc?95172</u>

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CIRCUIT CONFIGURATION	CIRCUIT CONFIGURATION					
CIRCUIT DESCRIPTION	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING				
Two diodes doubler circuit	D					
Two diodes common cathodes	С					
Two diodes common anodes	J					
Single diode	E	VSKE (2) 0 (3)				

LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95369		

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ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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